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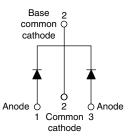
VS-32CTQ025PbF, VS-32CTQ025-N3, VS-32CTQ030PbF, VS-32CTQ030-N3

WISHAY. WS-32C I QU2 www.vishay.com

Vishay Semiconductors

Schottky Rectifier, 2 x 15 A





PRODUCT SUMMARY						
Package	TO-220AB					
I _{F(AV)}	2 x 15 A					
V _R	25 V, 30 V					
V_F at I_F	0.40 V					
I _{RM} max.	97 mA at 125 °C					
T _J max.	150 °C					
Diode variation	Common cathode					
E _{AS}	13 mJ					

FEATURES

- 150 °C T_J operation
- · Low forward voltage drop
- High frequency operation



 High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
 COMPLIANT
 COMPLIANT



- Guard ring for enhanced ruggedness and long FREE
 Available
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The VS-32CTQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	30	A			
V _{RRM}		25/30	V			
I _{FSM}	t _p = 5 μs sine	900	A			
V _F	15 A _{pk} , T _J = 125 °C	0.40	V			
TJ	Range	- 55 to 150	°C			

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-32CTQ025PbF	VS-32CTQ025-N3	VS-32CTQ030PbF	VS-32CTQ030-N3	UNITS		
Maximum DC reverse voltage	VR	25	25	30	30	v		
Maximum working peak reverse voltage	V _{RWM}	20	20	50	50			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at $T_C = 115$ °C	30				
Maximum peak one cycle non-repetitive surge current		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	900	А		
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	250			
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.20 A, L = 11.10 mH		13	mJ		
Repetitive avalanche current	I _{AR}		Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _B typical		А		

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VS-32CTQ025PbF, VS-32CTQ025-N3, VS-32CTQ030PbF, VS-32CTQ030-N3

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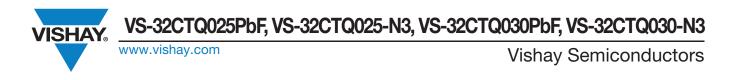
Vishay Semiconductors

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		15 A	T ₁ = 25 °C	0.49				
Maximum forward voltage drop	V _{FM} ⁽¹⁾	30 A	1j=23 0	0.58	V			
See fig. 1	VFM (**	15 A	T ₁ = 125 °C	0.40				
		30 A	- 1j = 125 C	0.53				
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C		1.75	mA			
See fig. 2	IRM \	T _J = 125 °C	$V_{\rm R}$ = Rated $V_{\rm R}$	97	III A			
Threshold voltage	V _{F(TO)}	T _{.1} = T _{.1} maximum		0.233	V			
Forward slope resistance	r _t	ij = ij maximum		9.09	mΩ			
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal ran	ge 100 kHz to 1 MHz) 25 °C	1300	pF			
Typical series inductance per leg	L _S	Measured lead to lead 5 m	nm from package body	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs			

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL	THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 150	°C				
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation See fig. 4	3.25	°C/W				
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	°C/W				
Approximate weight			2	g				
Approximate weight			0.07	oz.				
Mounting torgue			6 (5)	kgf ⋅ cm				
Mounting torque maximum			12 (10)	(lbf ⋅ in)				
Marking davias			32CT	Q025				
Marking device		Case style TO-220AB		Q030				



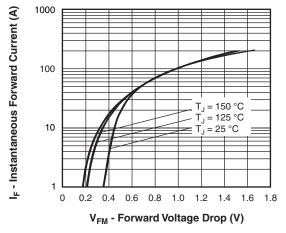


Fig. 1 - Maximum Forward Voltage Drop Characteristics

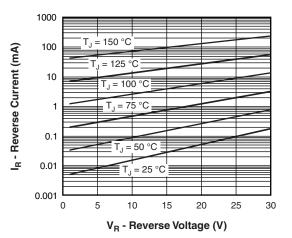


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

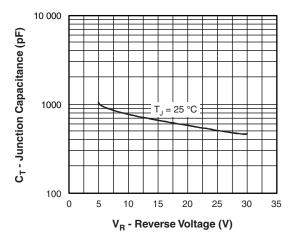
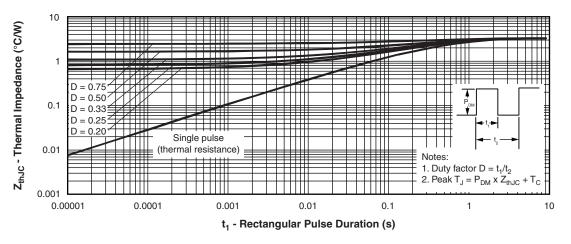
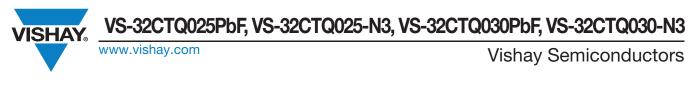


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





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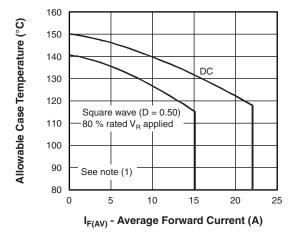


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

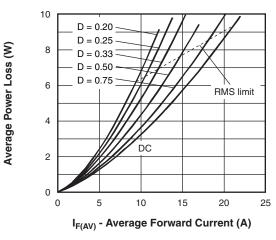
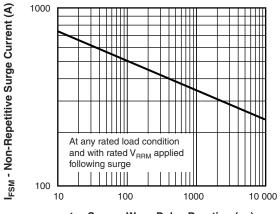
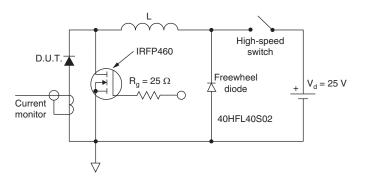


Fig. 6 - Forward Power Loss Characteristics



 t_p - Square Wave Pulse Duration (µs)

Fig. 7 - Maximum Non-Repetitive Surge Current





Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6);

 Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; $I_R \text{ at } V_{R1}$ = 80 % rated V_R

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VS-32CTQ025PbF, VS-32CTQ025-N3, VS-32CTQ030PbF, VS-32CTQ030-N3



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Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code	VS-	32	С	т	Q	030	PbF		
	1	2	3	4	5	6	7		
	1 · · · · · · · · · · · · · · · · · · ·	 Vishay Semiconductors product Current rating (30 A) Circuit configuration: C = Common cathode Package: T = TO-220 							
	5 6 7	- Volt - Env	T = TO-220 Schottky "Q" series Voltage ratings — Environmental digit • PbF = Lead (Pb)-free and RoHS				025 = 25 030 = 30 complia		

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-32CTQ025PbF	50	1000	Antistatic plastic tube			
VS-32CTQ025-N3	50	1000	Antistatic plastic tube			
VS-32CTQ030PbF	50	1000	Antistatic plastic tube			
VS-32CTQ030-N3	50	1000	Antistatic plastic tube			

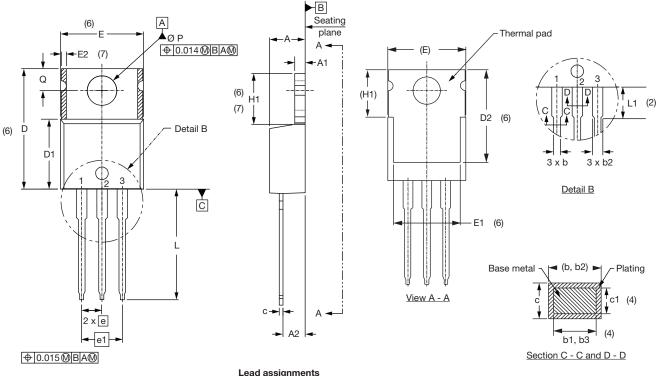
LINKS TO RELATED DOCUMENTS				
Dimensions		www.vishay.com/doc?95222		
Part marking information	TO-220AB PbF	www.vishay.com/doc?95225		
	TO-220AB -N3	www.vishay.com/doc?95028		

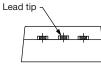


Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches





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	_										

<u>Diodes</u> 1. - Anode/open 2. - Cathode

2.	-	Cathode
3.	-	Anode

SYMBOL	MILLIM	IETERS	INC	NOTES	Γ	
	MIN.	MAX.	MIN.	MAX.	NOTES	
A	4.25	4.65	0.167	0.183		
A1	1.14	1.40	0.045	0.055		
A2	2.56	2.92	0.101	0.115]
b	0.69	1.01	0.027	0.040		1
b1	0.38	0.97	0.015	0.038	4	
b2	1.20	1.73	0.047	0.068		
b3	1.14	1.73	0.045	0.068	4]
С	0.36	0.61	0.014	0.024		
c1	0.36	0.56	0.014	0.022	4	
D	14.85	15.25	0.585	0.600	3	
D1	8.38	9.02	0.330	0.355		
D2	11.68	12.88	0.460	0.507	6	

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- ⁽³⁾ Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimensions: inches
- $^{\rm (6)}$ Thermal pad contour optional within dimensions E, H1, D2 and E1

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 0.414 10.11 10.51 0.398 Е 3,6 E1 6.86 8.89 0.270 0.350 6 E2 0.76 0.030 7 --2.41 2.67 0.095 0.105 е 0.208 e1 4.88 5.28 0.192 H1 6.09 6.48 0.240 0.255 6,7 13.52 14.02 0.532 0.552 Т 3.32 3.82 0.131 0.150 2 L1 ØΡ 3.54 3.73 0.139 0.147 0.102 Q 2.60 3.00 0.118 90° to 93° 90° to 93° θ

Conforms to JEDEC outline TO-220AB

- $^{(7)}$ Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- ⁽⁸⁾ Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



Vishay

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